# **Triacs**

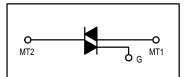
# **Silicon Bidirectional Triode Thyristors**

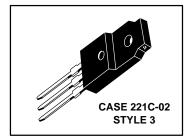
. . . designed primarily for industrial and consumer applications for full wave control of ac loads such as appliance controls, heater controls, motor controls, and other power switching applications.

- · All Diffused and Glass-Passivated Junctions for Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal resistance and High Heat Dissipation
- · Center Gate Geometry for Uniform Current Spreading
- Gate Triggering Guaranteed in Three Modes (MAC229FP Series) or Four Modes (MAC229AFP Series)

# MAC229FP Series MAC229AFP Series

TRIACs 8 AMPERES RMS 200 thru 800 VOLTS





#### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted.)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage <sup>(1)</sup> (T <sub>J</sub> = -40 to 110°C, 1/2 Sine Wave 50 to 60 Hz, Gate Open)  MAC229-4FP, MAC229A4FP  MAC229-6FP, MAC229A6FP  MAC229-8FP, MAC229A8FP  MAC229-10FP, MAC229A10FP	VDRM	200 400 600 800	Volts
On-State RMS Current (T <sub>C</sub> = 80°C) Full Cycle Sine Wave 50 to 60 Hz	I <sub>T</sub> (RMS)	8	Amps
Peak Non-repetitive Surge Current (One Full Cycle 60 Hz, T <sub>J</sub> = 110°C)	ITSM	80	Amps
Circuit Fusing (t = 8.3 ms)	l <sup>2</sup> t	26	A <sup>2</sup> s
Peak Gate Current (t ≤ 2 μs)	I <sub>GM</sub>	±2	Amps
Peak Gate Voltage (t ≤ 2 μs)	Vgм	±10	Volts
Peak Gate Power (t ≤ 2 μs)	P <sub>GM</sub>	20	Watts
Average Gate Power $(T_C = 80^{\circ}C, t \leq 8.3 \text{ ms})$	P <sub>G(AV)</sub>	0.5	Watts
Operating Junction Temperature Range	TJ	-40 to 110	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to 150	°C
Mounting Torque		8	in. lb.

<sup>1.</sup> V<sub>DRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

<sup>2.</sup> The case temperature reference point for all TC measurements is a point on the center lead of the package as close as possible to the plastic body.



## **MAC229FP Series MAC229AFP Series**

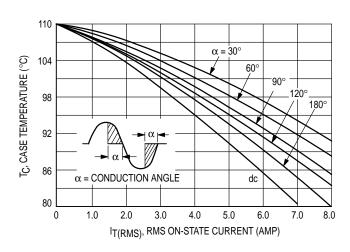
#### THERMAL CHARACTERISTICS

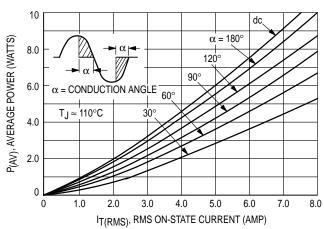
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	2.2	°C/W
Thermal Resistance, Case to Sink	$R_{\theta CS}$	2.2 (typ)	°C/W
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	60	°C/W

#### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C and either polarity of MT2 to MT1 voltage unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak Blocking Current(1) $(V_D = Rated V_{DRM}, Open Gate)$ $T_J = 25^{\circ}C$ $T_J = 110^{\circ}C$	IDRM	_	_	10 2	μA mA
Peak On-State Voltage (I <sub>TM</sub> = 11 A Peak, Pulse Width $\leq$ 2 ms, Duty Cycle $\leq$ 2%)	V <sub>TM</sub>		_	1.8	Volts
Gate Trigger Current (Continuous dc) $ (V_D = 12 \text{ V}, \text{ R}_L = 100 \Omega) \\ \text{MT2(+)}, \text{ G(+)}; \text{MT2(+)}, \text{ G(-)}; \text{MT2(-)}, \text{ G(-)} \\ \text{MT2(-)}, \text{ G(+) "A" Suffix Only} $	lGT	  -  -		5 10	mA
Gate Trigger Voltage (Continuous dc) $ (V_D = 12 \ V, \ R_L = 100 \ \Omega) $ $ MT2(+), \ G(+); \ MT2(+), \ G(-); \ MT2(-), \ G(-) $ $ MT2(-), \ G(+) \ "A" \ Suffix \ Only $ $ (V_D = Rated \ V_{DRM}, \ T_C = 110^{\circ}C, \ R_L = 10 \ k) $ $ MT2(+), \ G(+); \ MT2(+), \ G(-); \ MT2(-), \ G(-) $ $ MT2(-), \ G(+) \ "A" \ Suffix \ Only $	Vgт	  0.2 0.2	_ _ _ _	2 2.5 —	Volts
Holding Current (V <sub>D</sub> = 12 Vdc, I <sub>TM</sub> = 200 mA, Gate Open)	Ιн		_	15	mA
Gate-Controlled Turn-On Time ( $V_D = Rated V_{DRM}$ , $I_{TM} = 16 A Peak$ , $I_G = 30 mA$ )	tgt		1.5	_	μs
Critical Rate of Rise of Off-State Voltage (V <sub>D</sub> = Rated V <sub>DRM</sub> , Exponential Waveform, T <sub>C</sub> = 110°C)	dv/dt		25		V/µs
Critical Rate of Rise of Commutation Voltage ( $V_D$ = Rated $V_{DRM}$ , $I_{TM}$ = 11.3 A, Commutating di/dt = 4.1 A/ms, Gate Unenergized, $T_C$ = 80°C)	dv/dt(c)	_	5	_	V/µs

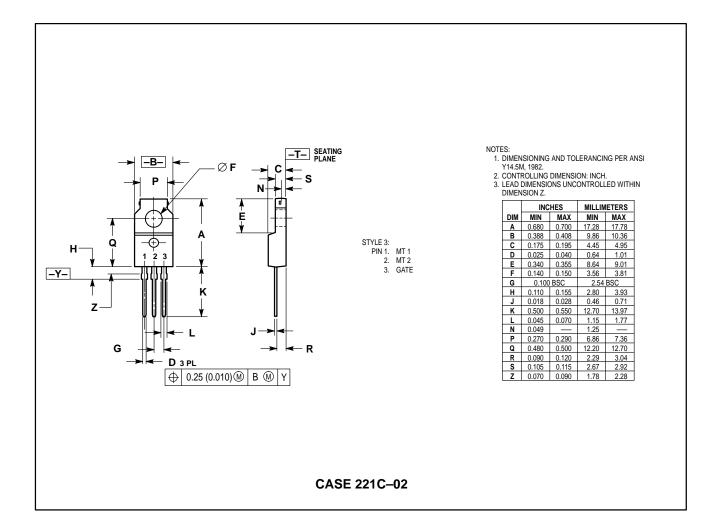
<sup>1.</sup> Ratings apply for open gate conditions. Devices shall not be tested with a constant current source for blocking voltage such that the voltage applied exceeds the rated blocking voltage.





## **MAC229FP Series MAC229AFP Series**

## **PACKAGE DIMENSIONS**



#### **MAC229FP Series MAC229AFP Series**

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